

**Claims:**

What is claimed is

1. A method of testing an optoelectronic device including a VCSEL, said VCSEL having a cavity resonator formed by a relatively low reflectivity frontside reflector and a relatively higher reflectivity backside reflector, comprising the steps of:
  4. at an intermediate stage of its assembly, measuring an optical signal leaking through 5. said backside reflector of said VCSEL,
  6. determining from the measured signal whether a selected quality of said VCSEL 7. meets a predetermined specification, and then
  8. finishing said device in a configuration designed to use radiation emitted from 9. said frontside reflector of said VCSEL.

1. The invention of claim 1 wherein said measuring step includes aligning a probe with  
2. said device and then measuring radiation leaking from backside reflectors of a multiplicity of  
3. VCSELs without performing another act of aligning said probe.

1. A method of testing a bottom-emitting VCSEL array at an intermediate stage of its manufacture, the VCSEL array including VCSELs each having a cavity resonator formed by a relatively low reflectivity frontside reflector and a relatively higher reflectivity backside reflector, comprising the steps of:
  5. aligning a probe with one side of said VCSEL array, said probe including electronic circuits coupled to each of said VCSELs for causing said VCSELs to emit radiation and including photodetection circuits coupled to each of said VCSELs for detecting radiation leaking through each of said backside reflectors,
  9. without performing another act of aligning said probe, determining from said detected 10. backside radiation whether a selected quality of each VCSEL meets a predetermined 11. specification, and then
  12. for those VCSEL arrays that meet specification, finishing their manufacture in a 13. configuration designed to use radiation emitted from said frontside reflectors.

1        4. The invention of claim 3 wherein said intermediate stage includes fabricating said  
2    VCSEL array on a substrate and said aligning and determining steps are performed without  
3    removing said substrate.

1        5. The invention of claim 4 wherein said finishing step includes removing said substrate  
2    before final assembly.

1        6. A method of testing a bottom-emitting VCSEL array at an intermediate stage of its  
2    manufacture, the VCSEL array including VCSELs each having a cavity resonator formed by a  
3    relatively low reflectivity frontside reflector and a relatively higher reflectivity backside  
4    reflector, comprising the steps of:

5              aligning a probe with said VCSEL array, said probe including a first array of electronic  
6    circuits coupled to one side of said VCSEL array and to each of said VCSELs for causing said  
7    VCSELs to emit radiation and including a second array of photodetection circuits, including  
8    photodetectors coupled to an opposite side of said VCSEL array and to each of said VCSELs for  
9    detecting radiation leaking through each of said backside reflectors,

10          without performing another act of aligning said probe, determining from said detected  
11    backside radiation whether a selected quality of each VCSEL meets a predetermined  
12    specification, said determining step including energizing said electronic and photodetection  
13    circuits in a fashion to reduce cross-talk between VCSELs and each photodetector, and then

14          for those VCSEL arrays that meet specification, finishing their manufacture in a  
15    configuration designed to use radiation emitted from said frontside reflectors.

1        7. The invention of claim 6 wherein said VCSELs are energized in a first predetermined  
2    sequence and said photodetection circuitry is energized in a second predetermined sequence so  
3    as to reduce cross-talk.

1        8. The invention of claim 7 wherein all of said VCSELs are energized concurrently, but  
2    said photodetection circuits are energized in a sequence that reduces said cross-talk.

1           9. The invention of claim 8 wherein said photodetection circuits are energized in a  
2 sequence that turns on a particular one of said circuits while concurrently turning off circuits  
3 adjacent thereto.

1           10. The invention of claim 7 wherein all of said photodetection circuits are energized  
2 concurrently, but said VCSELs are energized in a sequence that reduces said cross-talk.

1           11. The invention of claim 10 wherein said VCSELs are energized in a sequence that  
2 turns on a particular one of said VCSELs while concurrently turning off VCSELs adjacent  
3 thereto.

1           12. The invention of claim 7 wherein first groups of said VCSELs are energized in said  
2 first sequence and second groups of said circuitry are energized in said second sequence, with  
3 VCSELs in each of said first groups being energized concurrently with one another and circuits  
4 in each of said second groups being energized concurrently with one another.

1           13. The invention of claim 6 wherein said intermediate stage includes fabricating said  
2 VCSEL array on a substrate and said aligning and determining steps are performed without  
3 removing said substrate.

1           14. The invention of claim 13 wherein said finishing step includes removing said  
2 substrate before final assembly.

1           15. Apparatus for testing an optoelectronic device at an intermediate stage of its  
2 manufacture, said device including a VCSEL having a cavity resonator formed by a relatively  
3 low reflectivity frontside reflector and a relatively higher reflectivity backside reflector, said  
4 apparatus comprising:

5                 a probe including a photodetection circuitry for measuring an optical signal leaking  
6 through said backside reflector of said VCSEL, and  
7                 means for determining from the measured signal whether a selected quality of said  
8 VCSEL meets a predetermined specification.

1        16. The invention of claim 15 further including means for aligning said probe with said  
2 device just once and wherein said photodetection circuitry measures radiation leaking from  
3 backside reflectors of a multiplicity of said VCSELs.

1        17. Apparatus for testing a bottom-emitting VCSEL array at an intermediate stage of its  
2 manufacture, the VCSEL array including VCSELs formed on a substrate, each VCSEL having a  
3 cavity resonator formed by a relatively low reflectivity frontside reflector and a relatively higher  
4 reflectivity backside reflector, said apparatus comprising:

5              a probe including electronic circuits coupled to each of said VCSELs for causing said  
6 VCSELs to emit radiation and including photodetection circuits coupled to each of said VCSELs  
7 for detecting radiation leaking through each of said backside reflectors,  
8              means for aligning said probe just once with one side of said VCSEL array, and  
9              means for determining from said detected backside radiation whether a selected quality of  
10          each VCSEL meets a predetermined specification.

1        18. The invention of claim 17 wherein said aligning means and determining means  
2 function without removing said substrate.

1        19. Apparatus for testing a bottom-emitting VCSEL array at an intermediate stage of its  
2 manufacture when its substrate is intact, the VCSEL array including VCSELs each having a  
3 cavity resonator formed by a relatively low reflectivity frontside reflector and a relatively higher  
4 reflectivity backside reflector, said apparatus comprising:

5              a probe including a first array of electronic circuits coupled to one side of said VCSEL  
6 array and to each of said VCSELs for causing selected ones of said VCSELs to emit radiation  
7 and including a second array of photodetection circuits, including photodetectors coupled to an  
8 opposite side of said VCSEL array and to each of said VCSELs for detecting radiation leaking  
9 through each of said backside reflectors,  
10              means for aligning said probe just once with said VCSEL array, and  
11              means for determining from said detected backside radiation whether a selected quality of  
12          each VCSEL meets a predetermined specification, said determining means including means for

**13** energizing said electronic and photodetection circuits in a fashion to reduce cross-talk between  
**14** VCSELs and each photodetector.

**1**        20. The invention of claim 19 wherein said probe energizes said VCSELs in a first  
**2** predetermined sequence and said photodetection circuitry in a second predetermined sequence so  
**3** as to reduce cross-talk.

**1**        21. The invention of claim 20 wherein said probe energizes all of said VCSELs  
**2** concurrently, but energizes said photodetection circuits in a sequence that reduces said cross-  
**3** talk.

**1**        22. The invention of claim 21 wherein said probe energizes said photodetection circuits  
**2** in a sequence that turns on a particular one of said circuits while essentially simultaneously  
**3** turning off circuits adjacent thereto.

**1**        23. The invention of claim 20 wherein said probe energizes all of said photodetection  
**2** circuits concurrently but energizes said VCSELs in a sequence that reduces said cross-talk.

**1**        24. The invention of claim 23 wherein said probe energizes said VCSELs in a sequence  
**2** that turns on a particular one of said VCSELs while concurrently turning off VCSELs adjacent  
**3** thereto.

**1**        25. The invention of claim 20 wherein said probe energizes first groups of said VCSELs  
**2** in said first sequence and second groups of said circuitry in said second sequence, with VCSELs  
**3** in each of said first groups being energized concurrently with one another and circuits in each of  
**4** said second groups being energized concurrently with one another.